SK32A THRU SK3AA

SCHOTTKY BARRIER RECTIFIER Reverse Voltage - 20 to 100 V Forward Current - 3 A

Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction, majority carrier conduction
- Built-in strain relief, ideal for automated placement
- For surface mount applications
- Low profile package
- Low power loss, high efficiency
- High current capability , Low forward voltage drop
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

Mechanical Data

- Case: SMA (DO-214AC) molded plastic body
- Terminals: solder plated, solderable per MIL-STD-750, Method 2026
- Polarity: color band denotes cathode end

Absolute Maximum Ratings and Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, resistive or inductive load, For capacitive load, derate by 20%

capacitive load, derate by 20%									
Parameter	Symbols	SK32A	SK33A	SK34A	SK35A	SK36A	SK38A	SK3AA	Units
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	20	30	40	50	60	80	100	V
Maximum RMS Voltage	V _{RMS}	14	21	28	35	42	57	71	V
Maximum DC Blocking Voltage	V _{DC}	20	30	40	50	60	80	100	V
Maximum Average Forward Rectified Current 0.375" (9.5 mm) Lead Length	I _(AV)	3							А
Peak Forward Surge Current, 8.3 ms Single Half- sine-wave Superimposed on rated load (JEDEC method)	I _{FSM}	80							A
Maximum Forward Voltage at 3 A DC ¹⁾	V _F	0.55			0.75 0		0.	85	V
Maximum Reverse Current $T_A = 25 \circ C$ at Rated DC Blocking Voltage 1) $T_A = 100 \circ C$	I _R	0.5							mA
			20 10						
Typical Junction Capacitance ³⁾	CJ	250				160			pF
Typical Thermal Resistance 2)	R _{0JA}	88 28						°C/W	
Operating Junction Temperature Range	R _{θJL} T _J	- 65 to + 125 - 65 to + 150					°C		
	-							_	
Storage Temperature Range	Ts	- 65 to + 150						°C	

 $^{1)}$ Pulse test: 300 μs pulse width, 1% duty cycle.

 $^{2)}$ P.C.B. mounted with 0.55 X 0.55" (14 X 14 mm) copper pad areas.

³⁾ Measured at 1 MHz and applied reverse voltage of 4 V.

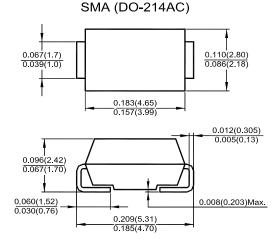


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Dimensions in inches and (millimeters)

FIG.1-FORWARD CURRENT DERATING CURVE

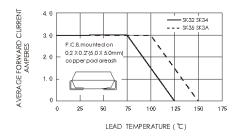


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

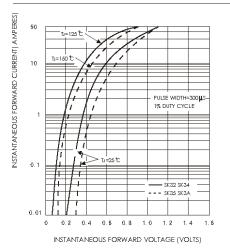


FIG.5-TYPICAL JUNCTION CAPACITANCE

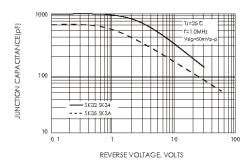


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

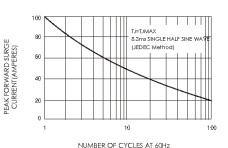
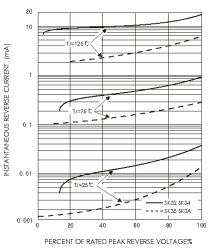
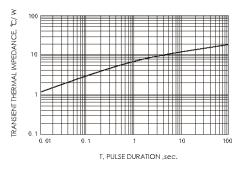


FIG.4-TYPICAL REVERSE CHARACTERISTICS









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